

UNISONIC TECHNOLOGIES CO., LTD

MGBR60L200C

Preliminary

DIODE

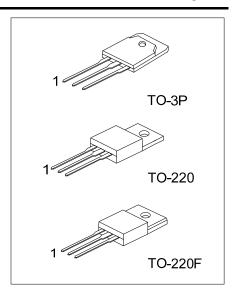
DUAL MOS GATED BARRIER RECTIFIER

■ DESCRIPTION

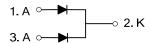
The UTC MGBR60L200C is a dual mos gated barrier rectifiers, it uses UTC's advanced technology to provide customers with low forward voltage drop and high switching speed, etc.

■ FEATURES

- * Low forward voltage drop
- * High switching speed



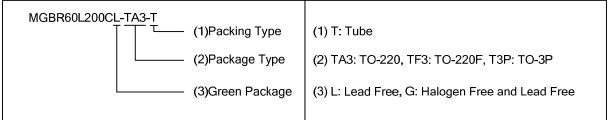
■ SYMBOL



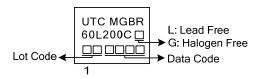
■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing	
Lead Free	Halogen Free	Fackage	1	2	3	Packing	
MGBR60L200CL-TA3-T	MGBR60L200CG-TA3-T	TO-220	Α	K	Α	Tube	
MGBR60L200CL-TF3-T	MGBR60L200CG-TF3-T	TO-220F	Α	K	Α	Tube	
MGBR60L200CL-T3P-T	MGBR60L200CG-T3P-T	TO-3P	Α	K	Α	Tube	

Note: Pin Assignment: A: Anode K: Cathode



■ MARKING



www.unisonic.com.tw 1 of 3

■ ABSOLUTE MAXIMUM RATINGS (PER LEG) (T_A=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

PARAMETER		SYMBOL	RATINGS	UNIT
DC Blocking Voltage		V_{RM}	200	V
Working Peak Reverse Voltage		V_{RWM}	200	V
Peak Repetitive Reverse Voltage		V_{RRM}	200	V
Average Rectified Output Current Per	Per Leg		30	Α
Device	Total	I _O	60	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load		I _{FSM}	300	Α
Operating Junction Temperature		T_J	-65~+150	°C
Storage Temperature		T_{STG}	-65~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL CHARACTERISTICS (PER LEG)

PARAMETER		SYMBOL	RATINGS	UNIT	
Junction to Ambient	TO-220/TO-220F	0	62.5	°C/W	
	TO-3P	θ _{JA}	21		
Junction to Case	TO-220		2		
	TO-220F	θ_{JC}	3.31	°C/W	
	TO-3P		1.55		

■ ELECTRICAL CHARACTERISTICS (PER LEG) (T_A =25°C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	$V_{(BR)R}$	I _R =0.50mA	200			V
Forward Voltage Drop	VEM	I _F =30A, T _J =25°C			0.95	V
		I _F =30A, T _J =125°C			0.85	V
Leakage Current (Note 1)	DM	V _R =200V, T _J =25°C			210	μΑ
		V _R =200V, T _J =125°C			27	mA

Notes: 1. Short duration pulse test used to minimize self-heating effect.

^{2.} Thermal resistance junction to case mounted on heatsink.

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